

DACO SEMICONDUCTOR**MB05S thru MB10S****0.8 A Single-Phase Glass Passivated Bridge Rectifiers**

Rectifier Reverse Voltage 50 to 1000V

Features

- This series is UL listed under the Recognized Component Index, file number E142814
- Ideal for surface mount application
- The plastic material used carries Underwriters Laboratory flammability recognition 94V-0
- Surge overload ratings to 30 amperes
- High temperature soldering guaranteed 265°C/10 seconds at 5 lbs (2.3kg) tension

Mechanical Data

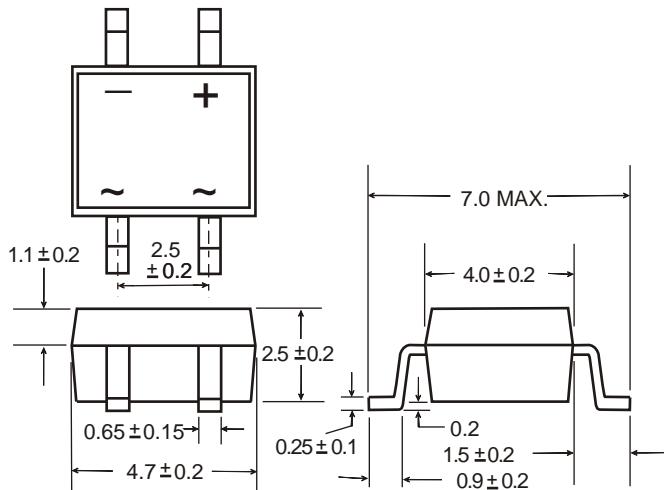
Case: Molded plastic

Terminals: Plated leads solderable per MIL-STD-202,
Method 208

Polarity: Marked on body

Mounting Position: Any

Weight: 0.0044 ounce, 0.125 grams (approx)



Dimensions in millimeters(1mm = 0.0394")

Maximum Ratings & Thermal Characteristics

Rating at 25°C ambient temperature unless otherwise specified, Resistive or Inductive load, 60 Hz.
For Capacitive load derate current by 20%.

Parameter	Sy	MB05S	MB1S	MB2S	MB4S	MB6S	MB8S	MB10S	unit
Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS bridge input voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V
Maximum average forward rectified output current at TA=40°C (*3)	IF(AV)				0.8				A
Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method)	IFSM				30				A
Rating for fusing (t<8.3ms)	I ² t				10				A ² sec
Typical thermal resistance per element(1)	ReJA				110				°C /W
Typical junction capacitance per element (2)	C _j				25.0				pF
Operating junction and storage temperature range	T _j , T _{TSG}				-55 to + 150				°C

Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified. Resistive or Inductive load, 60Hz.
For Capacitive load derate by 20 %.

Parameter	Symbol	MB05S	MB1S	MB2S	MB4S	MB6S	MB8S	MB10S	Unit
Maximum instantaneous forward voltage drop per leg at 0.5A	VF				1.1				V
Maximum DC reverse current at rated TA =25 °C DC blocking voltage per element TA =125 °C	IR				10 500				μA

Notes: (1)Thermal resistance from Junction to Ambient on P.C.board mounting.

(2)Measured at 2.0MHz and applied reverse voltage of 4.0 volts.

(3)R-load on aluminum substrate TA=25°C.

Rating and Characteristic Curves (TA=25°C Unless otherwise noted)
MB05S thru MB10S

Fig. 1 Derating Curve for Output Rectified Current

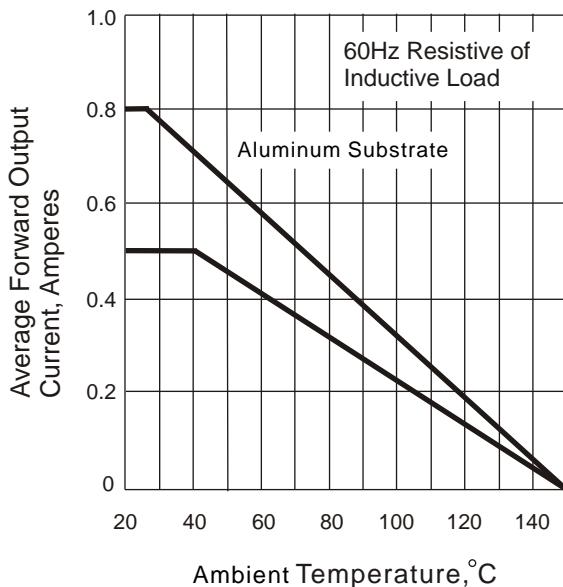


Fig. 2 Maximum Non-repetitive Peak Forward Surge Current

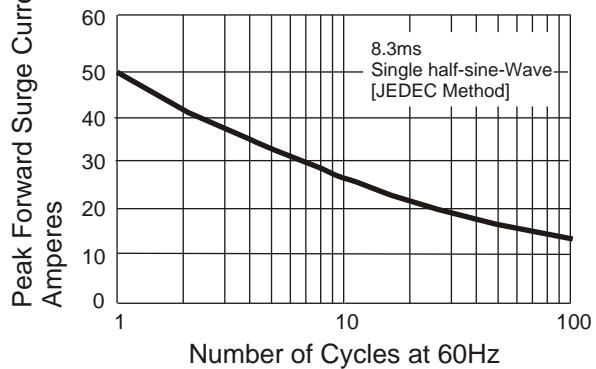


Fig. 3 Typical Instantaneous Forward Characteristics

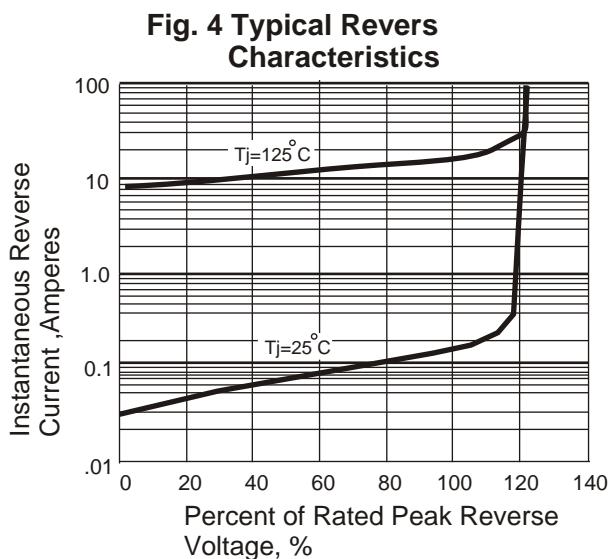
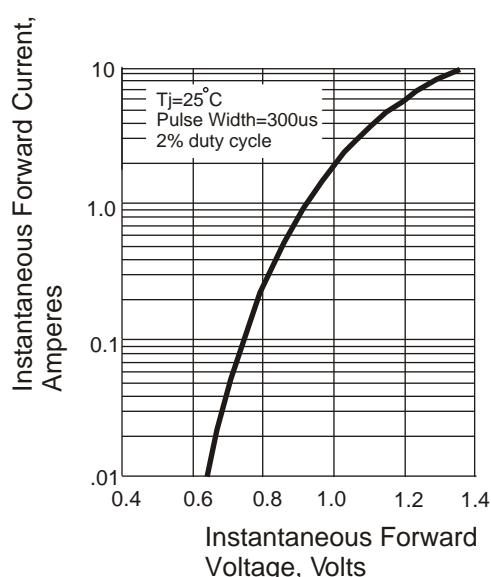


Fig. 5 Typical Junction Capacitance

